

Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings	Unit
V _{DSS}	250	V
V _{GSS}	±20	V
I _D	±7	A
I _{D(pulse)}	±15 (PW≤1ms, Du≤1%)	A
E _{AS} *	55	mJ
P _T	4 (Ta=25°C, with all circuits operating, without heatsink)	W
	35 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ _{JA}	31.2 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{JC}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
T _{ch}	150	°C
T _{stg}	-40 to +150	°C

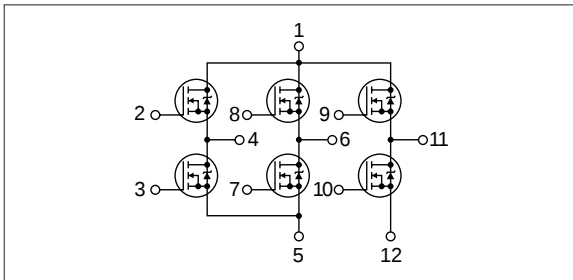
*: V_{DD}=25V, L=2.0mH, I_D=7A, unclamped, R_G=50Ω, see Fig. E on page 15.

Electrical characteristics

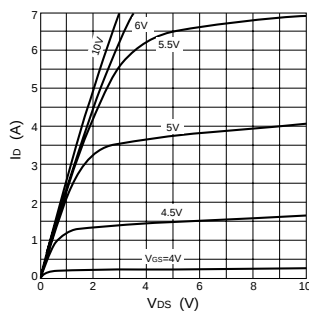
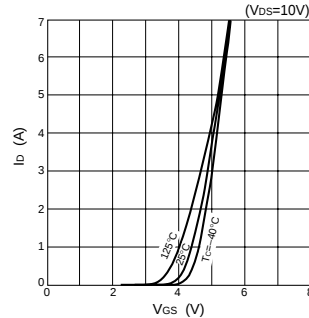
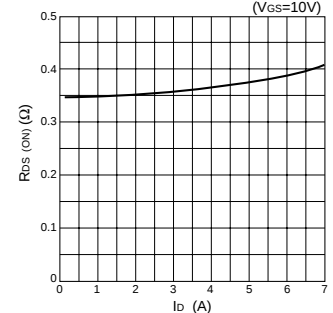
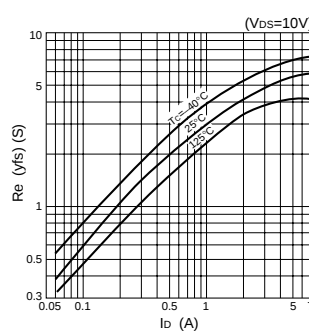
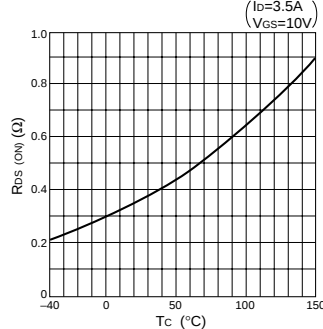
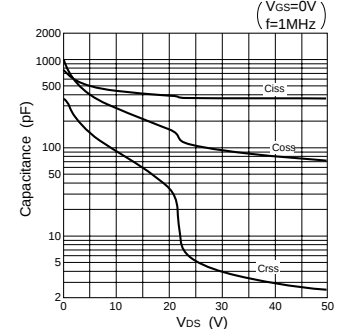
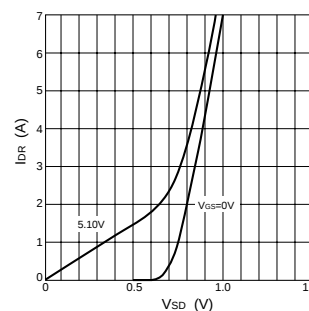
(Ta=25°C)

Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	250			V	I _D =100μA, V _{GS} =0V
I _{GSS}			±100	nA	V _{GS} =±20V
I _{DSS}			100	μA	V _{DS} =250V, V _{GS} =0V
V _{TH}	2.0		4.0	V	V _{DS} =10V, I _D =1mA
R _{e(yfs)}	2.5	5.0		S	V _{DS} =10V, I _D =3.5A
R _{DS(ON)}		0.4	0.5	Ω	V _{GS} =10V, I _D =3.5A
C _{iss}		450		pF	V _{DS} =10V, f=1.0MHz, V _{GS} =0V
C _{oss}		280		pF	V _{DS} =10V, f=1.0MHz, V _{GS} =0V
t _{d(on)}		20		ns	I _D =3.5A, V _{DD} ≐100V, R _L =28.6Ω, V _{GS} =10V, see Fig. 3 on page 16.
t _r		30		ns	I _D =3.5A, V _{DD} ≐100V, R _L =28.6Ω, V _{GS} =10V, see Fig. 3 on page 16.
t _{d(off)}		55		ns	I _D =3.5A, V _{DD} ≐100V, R _L =28.6Ω, V _{GS} =10V, see Fig. 3 on page 16.
t _f		75		ns	I _D =3.5A, V _{DD} ≐100V, R _L =28.6Ω, V _{GS} =10V, see Fig. 3 on page 16.
V _{SD}		1.0	1.5	V	I _{SD} =7A, V _{GS} =0V
t _{rr}		600		ns	I _{SD} =±100mA

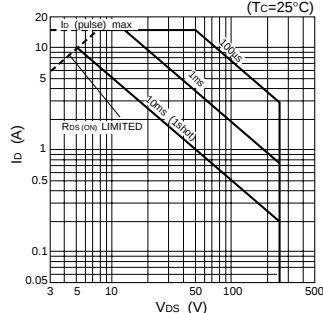
Equivalent circuit diagram



Characteristic curves

I_D-V_{DS} Characteristics (Typical)

I_D-V_{GS} Characteristics (Typical)

R_{DS(ON)}-I_D Characteristics (Typical)

R_{e(yfs)}-I_D Characteristics (Typical)

R_{DS(ON)}-T_C Characteristics (Typical)

Capacitance-V_{DS} Characteristics (Typical)

I_{DR}-V_{SD} Characteristics (Typical)


Safe Operating Area (SOA)


P_T-T_A Characteristics
